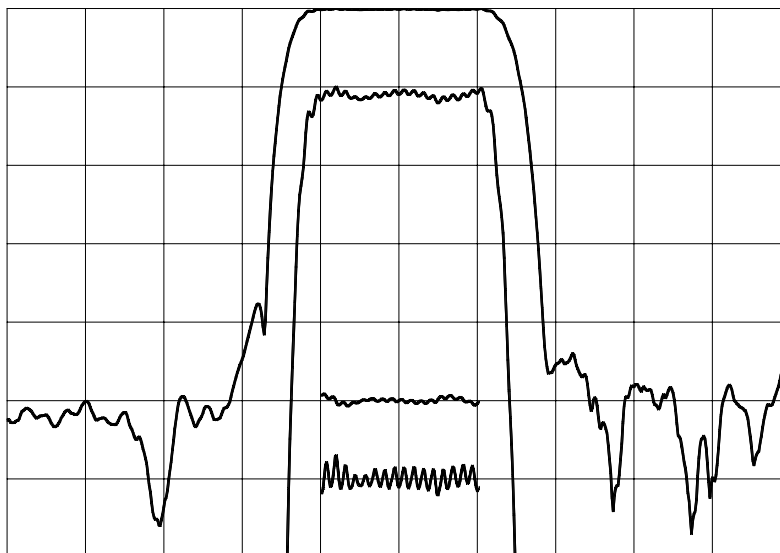


## TYPICAL PERFORMANCE



Horizontal: 4 MHz/div

Vertical (from top):

Magnitude

10,1 dB/div

Phase Deviation

10 deg/div

Group Delay Variation

50 ns/div

## SPECIFICATION

Parameter	Min	Typ	Max	Units
Center Frequency <sup>1</sup>	139.8	140	140.2	MHz
Insertion Loss		8.3	9.5	dB
1 dB Bandwidth	9.6	9.92		MHz
3 dB Bandwidth	10.5	10.9		MHz
35 dB Bandwidth		14.0	15	MHz
Passband Ripple <sup>2</sup>		0.25	1	dB
Phase Deviation from Linear <sup>2</sup>		3	6	deg
Group Delay Variation <sup>2</sup>		30	100	ns
Absolute Delay		1.0		us
Ultimate Rejection (30-350 MHz)	40			dB
Substrate Material	YZ Lithium Niobate			
Temperature Coefficient of Frequency (Tc) <sup>3</sup>		-94		ppm/°C
Ambient Temperature		25		°C
Source and Load Impedance		50		Ω

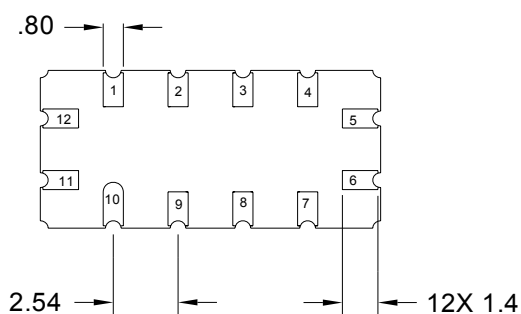
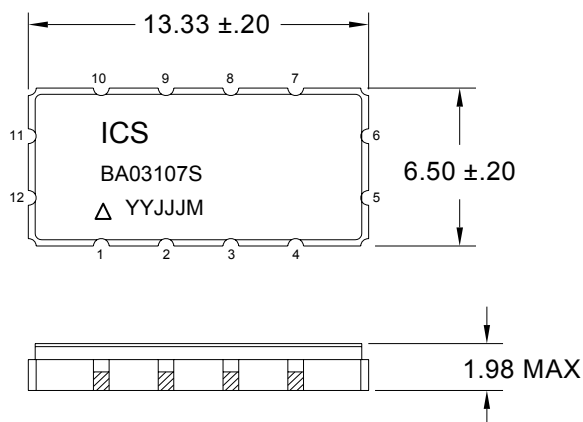
Notes: 1. Average of lower & upper 3 dB frequencies.

2. Evaluated over 80% of the 3 dB bandwidth.

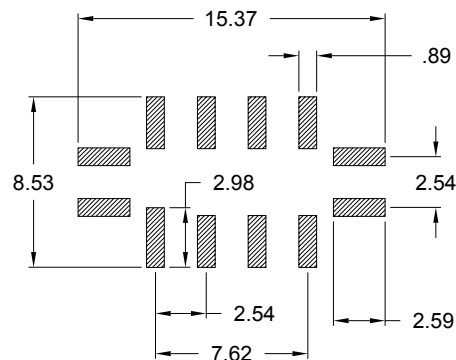
3. Typical change of filter frequency response with temperature is  $\Delta f/f_{ref} = (T-T_{ref}) \cdot Tc$  ppm.

## PACKAGE AND SUGGESTED PCB FOOTPRINT

### PACKAGE INFORMATION



### SUGGESTED PCB FOOTPRINT

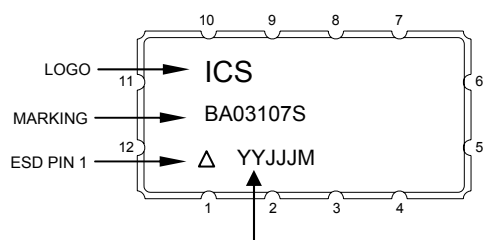


PIN CONFIGURATION	
11	INPUT
12	INPUT RETURN
5	OUTPUT
6	OUTPUT RETURN
ALL OTHERS	GROUND

NOTES:  
DIMENSIONS SHOWN ARE NOMINAL IN MILLIMETERS. ALL TOLERANCES ARE ±0.15MM EXCEPT OVERALL LENGTH AND WIDTH

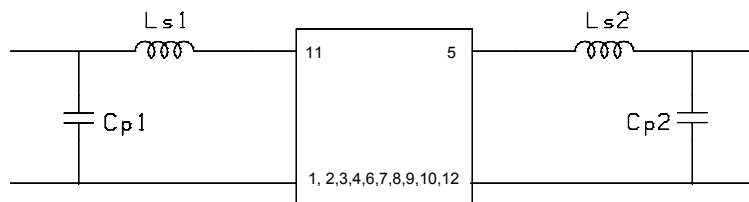
Package Material:  
Body:  $Al_2O_3$  ceramic  
Lid: Kovar, Ni plated  
Terminations: Au plating 1 µm min, over a 1.3-8.9 µm Ni plating

### MARKING



The date code consists of:  
YY = last two digits of year; JJJ = Julian day;  
M = manufacturing site code

## MATCHING CIRCUIT



Component values in 50  $\Omega$ :  
(Minimum Q = 40)

Ls1 = 68 nH  
Cp1 = 15 pF

Ls2 = 100 nH  
Cp2 = 10 pF

### Notes:

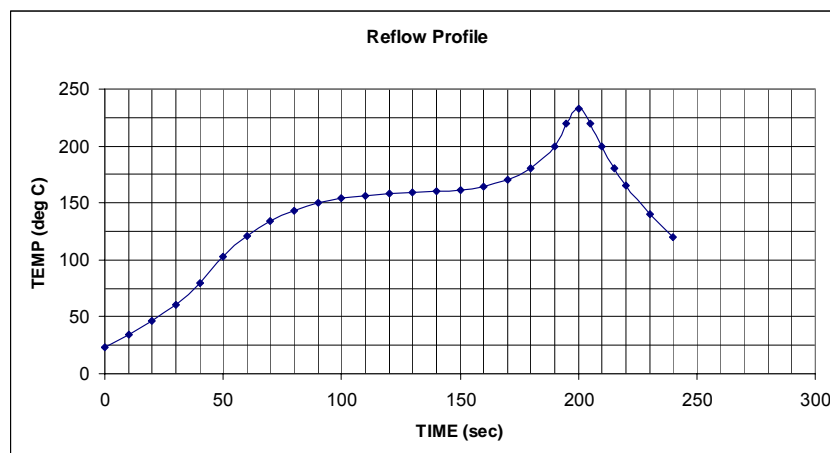
- Optimum values may differ from these when using a different fixture or board layout. The values shown here are intended as a guide only.

## MAXIMUM RATINGS

Parameter	Min	Max	Units
Storage Temperature Range	-45	+85	$^{\circ}\text{C}$
Maximum Input Power Level		15	dBm
D. C. Voltage between Each Terminal		15	V

## PHYSICAL AND ENVIRONMENTAL CHARACTERISTICS

Parameter	Qualification Conditions
Life Testing	High temperature bake at +85 °C for 168 hours.
Temperature Cycling	MIL-STD 883, Method 1010: -40 °C to +85 °C, 10 cycles, 10 minutes dwell at temperature extremes
Vibration	MIL-STD-202, Method 201A: 10 to 55 Hz, double amplitude of 0.06" for 2 hours in each axis.
Mechanical Shock	MIL-STD-883, Method 2002, Test Condition B: 1500 g, 3 impacts each axis
Solder Heat Resistance and Reflow Condition	Peak temperature 240+/-5 °C for 10 seconds. Pre-heat: 150-170 °C for 60 to 90 seconds. Peak dwell: over 200 °C for 23 to 26 seconds. Handling: Class 1 per MIL-STD-1686 Reflow Profile is shown at the bottom of this table.
Lead Integrity	MIL-STD 883 Method 2004, Condition D 8 oz for 30 seconds.
Solderability	MIL-STD-883 Method 2003: 245 °C +/-5 °C; 95% coverage; no steam aging
Hermeticity	MIL-STD 883 Method 1014: Condition A2 and Condition C (no bomb)
ESD Classification	Class I per MIL-STD-883 Method 3015
Precautions	Do not subject devices to ultrasonic cleaning, which may cause deterioration and destruction of the device.



ISO 9001  
Registered

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